

STRUCTURE Silicon Monolithic Integrated Circuit
 NAME OF PRODUCT DC-AC Inverter Control IC

TYPE **BD9243MUV**

- FUNCTION
- 36V High voltage process
 - 1ch control with Full-Bridge
 - Lamp current and voltage sense feed back control
 - Sequencing easily achieved with Soft Start Control
 - Short circuit protection with Timer Latch
 - Under Voltage Lock Out
 - Circuit protection with quick Shutdown
 - Mode-selectable the operating or stand-by mode by stand-by pin
 - BURST mode controlled by PWM and DC input
 - VQFN024V4040 small package

○Absolute Maximum Ratings (T_a = 25°C)

Parameter	Symbol	Limits	Unit
Supply Voltage	VCC	36	V
BST PIN	BST	40	V
SW PIN	SW	36	V
BST-SW voltage difference	BST-SW	15	V
Operating Temperature Range	T _{opr}	-40~+85	°C
Storage Temperature Range	T _{stg}	-55~+150	°C
Maximum Junction Temperature	T _{jmax}	+150	°C
Power Dissipation	P _d	700*	mW

*P_d derate at 5.6mW/°C for temperature above T_a = 25°C (When mounted on a PCB 70.0mm×70.0mm×1.6mm)

○Operating condition

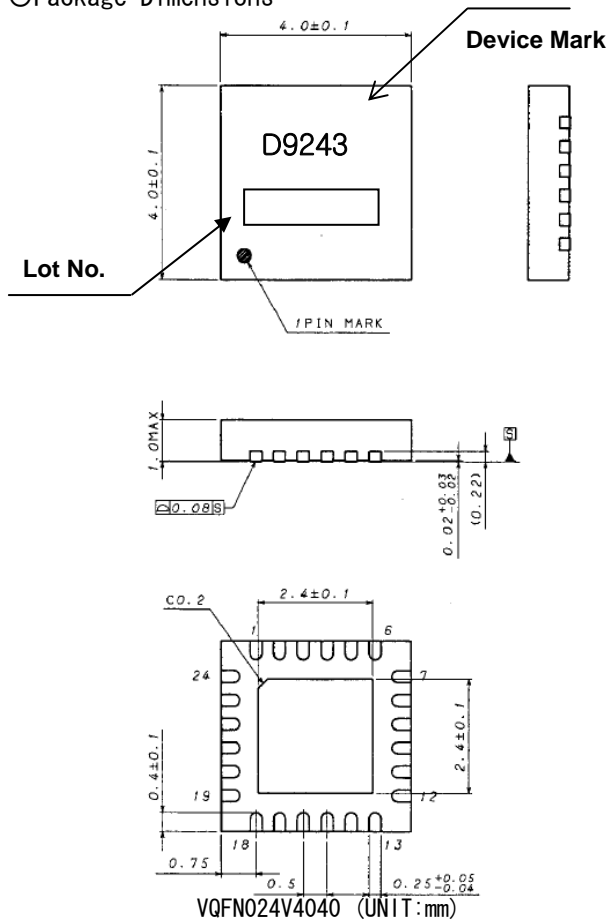
Parameter	Symbol	Limits	Unit
Supply voltage	VCC	8.0~30.0	V
BST voltage	BST	5.0~37.5	V
BST-SW voltage difference	BST-SW	5.0~14.0	V
oscillation frequency	F _{OUT}	30~110	kHz
BCT oscillation frequency	f _{BCT}	0.05~1.00	kHz

OElectric Characteristics (Ta=25°C, VCC=24V, STB=3.0V)

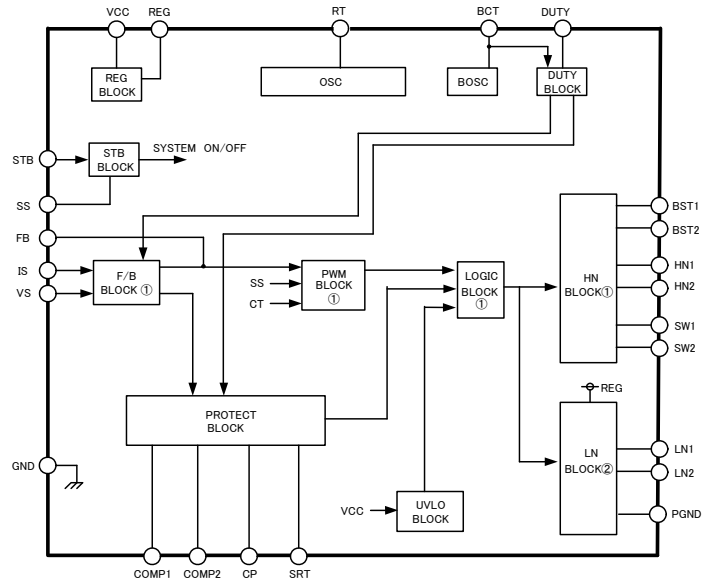
Parameter	Symbol	Limits			Unit	Conditions
		MIN.	TYP.	MAX.		
((WHOLE DEVICE))						
Operating current	Icc1	—	2.2	5.0	mA	FOUT=60kHz, FB=SW=GND, BST=OPEN
Stand-by current	Icc2	—	0	10	μA	
((STAND BY CONTROL))						
Stand-by voltage H	VstH	2.0	—	VCC	V	System ON
Stand-by voltage L	VstL	-0.3	—	0.8	V	System OFF
((VCC UVLO BLOCK))						
Operating voltage (VCC)	V_VCCUVP	6.17	6.50	6.83	V	
Hysteresis width (VCC UVLO)	ΔV_VCCUVP	0.37	0.50	0.63	V	
((REG BLOCK))						
REG output voltage	VREG	7.35	7.50	7.65	V	VCC>8.5V, I _o =10mA
REG source current	I _{REG}	20	—	—	mA	
((OSC BLOCK))						
RT Output Voltage	V _{RT}	1.05	1.50	1.95	V	
SRT ON Resistor value	R _{SRT}	—	100	200	Ω	
((SOFT START BLOCK))						
Soft start Charge Current	TSS	1.5	2.0	2.5	μA	
SS term start voltage	V _{SS_ST}	0	50	150	mV	
SS term end voltage	V _{SS_END}	2.8	3.0	3.2	V	
((BOSC BLOCK))						
BOSC Max voltage	V _{BCTH}	1.94	2.00	2.06	V	f _{BCT} =0.3kHz
BOSC Min voltage	V _{BCTL}	0.4	0.5	0.6	V	f _{BCT} =0.3kHz
BOSC frequency	f _{BCT}	291	300	309	Hz	C _{BCT} =10000pF
((FEED BACK BLOCK))						
IS threshold voltage	V _{IS}	1.225	1.250	1.275	V	
VS threshold voltage	V _{VS}	1.215	1.250	1.285	V	
IS source current 1	I _{IS1}	—	—	0.9	μA	DUTY=2.2V
IS source current 2	I _{IS2}	40	50	60	μA	DUTY=0V IS=1.0V
VS source current	I _{VS}	—	—	0.9	μA	
IS COMP detect voltage	V _{ISCOMP}	0.606	0.625	0.644	V	
((OUTPUT BLOCK))						
LN output sink resistance	R _{sinkLN}	1.5	3	6	Ω	
LN output source resistance	R _{sourceLN}	5	10	20	Ω	
HN output sink resistance	R _{sinkHN}	1.5	3	6	Ω	V _{BST} -V _{SW} =7.0V
HN output source resistance	R _{sourceHN}	5	10	20	Ω	V _{BST} -V _{SW} =7.0V
MAX DUTY	MAX DUTY	46.0	48.5	49.5	%	FOUT=60kHz, SW=GND, BST=OPEN
OFF period	T _{OFF}	100	200	400	ns	SW=GND, BST=OPEN
Drive output frequency	F _{OUT}	57.9	60.0	62.1	kHz	RT=82kΩ
((TIMER LATCH BLOCK))						
CP timer latch detect voltage	V _{CP}	1.9	2.0	2.1	V	
CP timer latch charge current	I _{CP}	0.85	1.0	1.15	μA	
((COMP BLOCK))						
COMP1 over voltage detect voltage	V _{COMP1}	3.88	4.00	4.12	V	
Hysteresis width (COMP1)	ΔV _{COMP1}	0.15	0.20	0.25	V	
COMP2 over voltage detect voltage	V _{COMP2}	3.88	4.00	4.12	V	

(This product is not designed to be radiation-resistant.)

○Package Dimensions



○Block Diagram



○Pin Description

PIN No.	PIN NAME	FUNCTION	PIN No.	PIN NAME	FUNCTION
1	GND	Ground	13	BST1	Boot-strap input for HN1 output
2	BCT	External capacitor between BCT and GND for adjusting the BURST triangle oscillator	14	REG	Regulator output
3	DUTY	Control Burst-dimming by PWM signal or DC	15	LN1	NMOS FET driver (Ch. 1)
4	SS	External capacitor between SS and GND for Soft Start Control and detect the time of Soft Start	16	PGND	Power Ground for FET drivers
5	CP	External capacitor between CP and GND for timer latch	17	LN2	NMOS FET driver (Ch. 2)
6	FB	Error amplifier output	18	BST2	Boot-strap input for HN2 output
7	IS	Error amplifier input 2	19	HN2	NMOS FET driver (Ch. 2)
8	VS	Error amplifier input 1	20	SW2	Lower rail voltage for HN2 output
9	COMP2	Input of over voltage detector2	21	VCC	Power supply input with UVLO Protection
10	COMP1	Input of over voltage detector1	22	STB	Stand-by switch
11	SW1	Lower rail voltage for HN1 output	23	SRT	External resistor from SRT to RT for adjusting the start-up Triangle oscillator
12	HN1	NMOS FET driver (Ch. 1)	24	RT	External resistor between RT and GND for adjustment frequency of saw tooth wave

○NOTE FOR USE

1. When designing the external circuit, including adequate margins for variation between external devices and IC. Use adequate margins for steady state and transient characteristics.
 2. The circuit functionality is guaranteed within of ambient temperature operation range as long as it is within recommended operating range. The standard electrical characteristic values cannot be guaranteed at other voltages in the operating ranges, however the variation will be small.
 3. Mounting failures, such as misdirection or miscounts, may harm the device.
 4. A strong electromagnetic field may cause the IC to malfunction.
 5. The GND pin should be the location within $\pm 0.3V$ compared with the PGND pin.
 6. If the voltage between VCC and I/O pins or GND and I/O pins is in opposite from the normal potential difference, unusual current flow into pins may occur which can destroy the IC. To avoid such occurrence it is recommended to place protection diodes for prevention against backward current flow.
 7. BD9243MUV incorporate a built-in thermal shutdown circuit (TSD circuit). The thermal shutdown circuit (TSD circuit) is designed only to shut the IC off to prevent runaway thermal operation. It is not designed to protect the IC or guarantee its operation of the thermal shutdown circuit is assumed.
 8. Absolute maximum ratings are those values that, if exceeded, may cause the life of a device to become significantly shortened. Moreover, the exact failure mode caused by short or open is not defined. Physical countermeasures, such as a fuse, need to be considered when using a device beyond its maximum ratings.
 9. About the external FET, the parasitic Capacitor may cause the gate voltage to change, when the drain voltage is switching. Make sure to leave adequate margin for this IC variation.
 10. By STB voltage, BD9243MUV are changed to 2 states. Therefore, do not input STB pin voltage between one state and the other state (0.8~2.0V).
 11. The pin connected a connector need to connect to the resistor for electrical surge destruction.
 12. This IC is a monolithic IC which (as shown is Fig. 4) has P⁺ substrate and between the various pins. A P-N junction is formed from this P layer of each pin. For example, the relation between each potential is as follows,
 - (When GND > PinB and GND > PinA, the P-N junction operates as a parasitic diode.)
 - (When PinB > GND > PinA, the P-N junction operates as a parasitic transistor.)
- Parasitic diodes can occur inevitably in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits as well as operation faults and physical damage. Accordingly you must not use methods by which parasitic diodes operate, such as applying a voltage that is lower than the GND (P substrate) voltage to an input pin

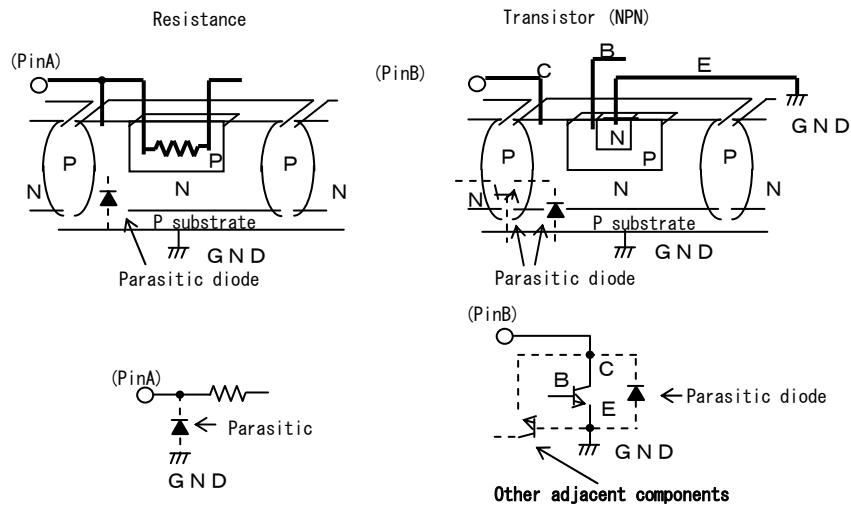


Fig. 4. Simplified structure of a Bipolar IC

Notes

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